NSN 5961-01-387-0159

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-387-0159 **Inclosure Material:** Plastic **Overall Length:** 0.620 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.36 forward voltage, dc and 2.66 forward voltage, dc **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector megawatts **Capacitance Rating In Picofarads:** 20.0 **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 95105-353-3610 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: